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SURFACE MOUNT PNP SILICON QUAD TRANSISTORS



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DESCRIPTION:

The CENTRAL SEMICONDUCTOR MMPQ2907A, consisting of four transistors and available in the SOIC-16 surface mount package, is designed for general purpose amplifier and switching applications.

MARKING: FULL PART NUMBER

MAXIMUM RATINGS: (T _A =25°C)	SYMBOL		UNITS
Collector-Base Voltage	V _{CBO}	60	V
Collector-Emitter Voltage	VCEO	60	V
Emitter-Base Voltage	VEBO	5.0	V
Continuous Collector Current	I _C	600	mA
Power Dissipation	PD	1.0	W
Operating and Storage Junction Temperature	T _{J,} T _{stq}	-55 to +150	°C
Thermal Resistance (Total Package)	Θ _{JA}	125	°C/W
Thermal Resistance (Each Transistor)	Θ_{JA}	240	°C/W

ELECTRICAL CHARACTERISTICS : (T _Δ =25°C ι	unless otherwise noted)
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SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
ICEV	V _{CE} =30V, V _{BE} =0.5V			50	nA
ICBO	V _{CB} =50V			20	nA
	V _{CB} =50V, T _A =125°C			20	μΑ
	Ι _C =10μΑ	60			V
BVCEO		60			V
BVEBO		5.0			V
V _{CE(SAT)}	I _C =150mA, I _B =15mA			0.4	V
V _{CE} (SAT)	I _C =500mA, I _B =50mA			1.6	V
V _{BE} (SAT)	I _C =150mA, I _B =15mA			1.3	V
V _{BE} (SAT)	I _C =500mA, I _B =50mA			2.6	V
h _{FE}	V _{CE} =10V, I _C =0.1mA	75			
	V _{CE} =10V, I _C =1.0mA	100			
h _{FE}	V _{CE} =10V, I _C =10mA	100			
	V _{CE} =10V, I _C =150mA	100		300	
	V _{CE} =10V, I _C =500mA	50			
	V _{CE} =20V, I _C =50mA, f=100MHz		250		MHz
	V _{EB} =2.0V, f=100kHz		12		pF
Cob	V _{CB} =10V, f=100kHz		6.0		pF
t _{on}	V _{CC} =30V, I _C =150mA, I _{B1} =15mA		30		ns
^t d	V _{CC} =30V, I _C =150mA, I _{B1} =15mA		8.0		ns
	V _{CC} =30V, I _C =150mA, I _{B1} =15mA		20		ns
t _{off}	V _{CC} =6.0V, I _C =150mA, I _{B1} =I _{B2} =15mA		80		ns
t _s	V _{CC} =6.0V, I _C =150mA, I _{B1} =I _{B2} =15mA		60		ns
^t f	V _{CC} =6.0V, I _C =150mA, I _{B1} =I _{B2} =15mA		20		ns
					R2 (1-March 2010)

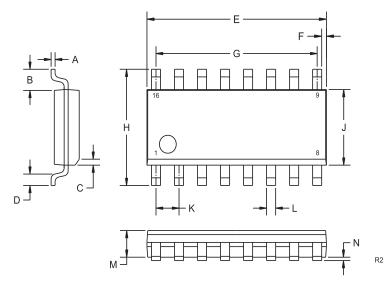




MMPQ2907A

SURFACE MOUNT PNP SILICON QUAD TRANSISTORS

SOIC-16 CASE - MECHANICAL OUTLINE



MARKING: FULL PART NUMBER

DIMENSIONS							
	INCHES		MILLIMETERS				
SYMBOL	MIN	MAX	MIN	MAX			
А	0.007	0.010	0.19	0.25			
В	0.041		1.04				
С	0.010	0.020	0.25	0.50			
D	0.020	0.035	0.50	0.90			
E	0.386	0.394	9.80	10.00			
F	0.010		0.25				
G	0.350		8.89				
Н	0.228	0.244	5.80	6.20			
J	0.150	0.157	3.80	4.00			
K	0.050		1.27				
Ĺ	0.0138	0.0201	0.35	0.51			
М	0.0531	0.0689	1.35	1.75			
N	0.0039	0.0098	0.10	0.25			
SOIC 16 (PE\/·P2)							

SOIC-16 (REV:R2)

R2 (1-March 2010)

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